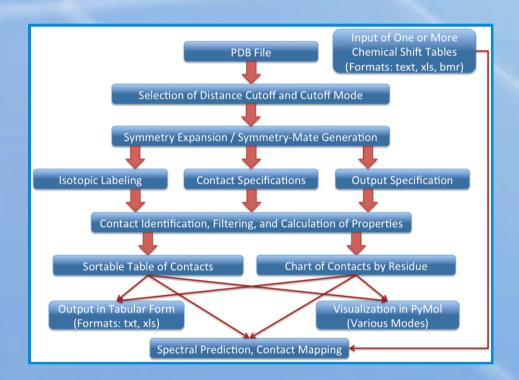




## Journal of Crystallization Process and Technology





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## **TABLE OF CONTENTS**

Volume 3	Number 1	January 2013
The Oleic Ac	cid Composition Effect on the Carboxymethyl Cellulose Based Biopolymer	Electrolyte
M. N. Chai,	M. I. N. Isa	1
Dielectric and	d Optical Characterization of Boron Doped Ammonium Dihydrogen Phosp	phate
D. Zion, S. I	Devarajan, T. Arunachalam	5
ACCEPT-NN	MR: A New Tool for the Analysis of Crystal Contacts and Their	
Links to NM	R Chemical Shift Perturbations	
I. V. Sergeye	v, A. E. McDermott	12
Crystallizatio	on and Characterization of a New Fluorescent Molecule Based on Schiff Ba	ise
D. H. Zhang,	X. Y. Zhang	28
Synthesis, Sp	${f pectral}$ Characterization and Ligation of N-[2-(Phenylseleno)ethyl]phthalin	nide
R. Rastogi, S	S. K. Srivastava, S. Asolia, R. J. Butcher	31
Structural, M	Morphological, Optical and Electrical Properties of Zn <sub>(1-x)</sub> Cd <sub>x</sub> O Solid	
Solution Gro	own on a- and r-Plane Sapphire Substrate by MOCV	
Λ Fouzri M	A Roukadhaha A H Tauré N Sakly A Robetnia V Sallet	36

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The journal publishes the highest quality original full articles, communications, notes, reviews, special issues and books, covering both the experimental and theoretical aspects including physical, chemical, and biological phenomena and processes related to the design, growth, and application of crystalline materials. Contributions can concern also with the fundamental concepts of crystal growth and the understanding of the relationship between crystal growth conditions and resulting properties of the crystal:

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